25 mm (1") encapsulated photomultiplier 9110V16 series data sheet



1 description

The 9110V16 encapsulated photomultiplier comprises a 25mm (1") diameter, compact, rugged, end window photomultiplier with a plano-concave window, high temperature blue-green sensitive bialkali photocathode and 10 BeCu dynodes of circular focused design.

The photomultiplier is encapsulated, together with a voltage divider, in a mumetal* sleeve.

This type will operate up to 90°C and has a minimum plateau length of 150 V at 90°C.

2 applications

- oil well logging including measuring while drilling (MWD)
- x-ray and gamma ray spectroscopy in harsh environments

3 features

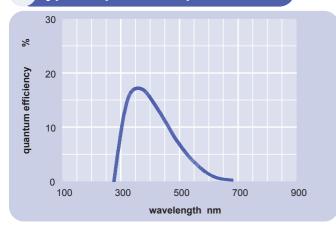
- rugged
- · high temperature operation
- encapsulated in a mu-metal sleeve with an integral voltage divider

4 window characteristics

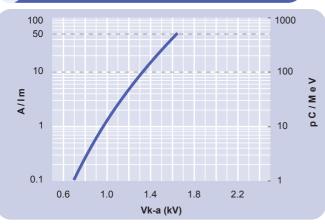
	9110V02 borosilicate
spectral range* (nm) refractive index (n _d)	280 - 630 1.49
K (ppm) Th (ppb) U (ppb)	300 250 100

* wavelength range over which quantum efficiency exceeds 1 % of peak

5 typical spectral response curves



6 typical voltage gain characteristics



6 characteristics

photocathode: high temperature bialkali active diameter quantum efficiency at peak luminous sensitivity with CB filter with CR filter dynodes: 10CFBeCu	mm % μΑ/Im	4	22 17 50 6 5	
anode sensitivity: nominal anode sensitivity max. rated anode sensitivity overall voltage for nominal A/Im overall voltage for max. rated A/Im gain at nominal A/Im dark current at 20 °C:	A/lm A/lm V V x 10 ⁶		10 50 1350 1650 0.2	1500
DC at nominal A/Im DC at max. rated A/Im pulsed linearity (-5 % deviation): divider A	nA nA mA		0.1 0.5 20	1
resolution: ¹³⁷ Cs with 1.0 " dia x 1.5 " Nal(TI) temperature coefficient: timing:	% °C ⁻¹		10 -0.5	
multi-electron rise time multi-electron fwhm single electron rise time transit time weight:	ns ns ns ns		2 4 1.8 15 64	
maximum ratings: anode current cathode current gain sensitivity	μΑ nA x 10 ⁶ A/Im pC/MeV			100 20 1 50 500
temperature V (k-a) ¹⁾ V (k-d1) V (d-d) ²⁾ ambient pressure (absolute)	°C V V V kPa	-55		90 2300 450 300 202

 $[\]stackrel{(1)}{\text{subject to not exceeding max. rated sensitivity}} \stackrel{(2)}{\text{subject to not exceeding max rated V(k-a)}}$

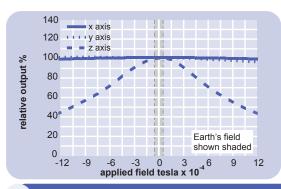
qualification shock & vibration levels (all 3 axes, non-operating

random vibration: 5 Hz to 100 Hz roll on 50 Hz to 500 Hz 500 Hz to 1000 Hz roll off composite duration sine vibration:	6 dB/octave 0.89 g²/Hz 6 dB/octave 25 g rms 60 mins/axis
amplitude frequency range sweep rate duration shock (half sine wave): 0.5 ms duration 4 ms duration shocks per axis	30 g 50 Hz to 2000 Hz 2 octaves/min 60 mins/axis 1000 g peak 250 g peak 3 up, 3 down

microphony under random vibration (all 3 axes, operating)

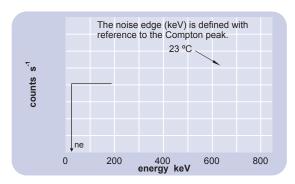
random vibration: 20 to 100 Hz roll on 100 to 400 Hz 400 to 500 Hz roll off	6 dB/octave 0.103 g²/Hz 6 dB/octave
composite duration microphony at 100 pC/MeV above a threshold of 5.5 pC (55 keV)	6.5 g rms 5 mins/axis < 1 cps

magnetic field sensitivity



pulse height resolution with NaI(TI) crystal

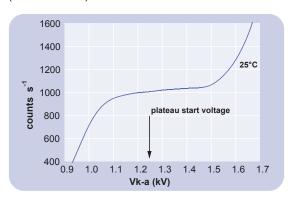
This pmt is tested for resolution at room temperature and at high temperature.



spectral data				
operating voltage for 13 pC/MeV operating voltage for 100 pC/MeV pulse height resolution noise edge	V V % keV	1050 1350 10 <10	1200 1500	1200 1500 14 35

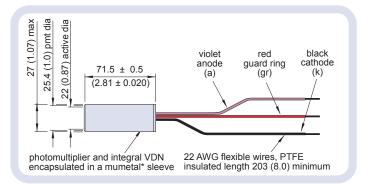
10 pulse counting with NaI(TI) crystal

Pulse counting plateau with 137Cs and Nal(TI) crystal (1.0" dia. x 1.5")

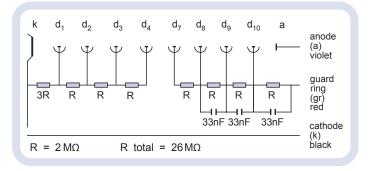


plateau data		90 min	°C typ	max
combined 25 °C / 90 °C: plateau start (1.5 pC threshold) plateau length ±5 %	V V	150	1250	1500

11 external dimensions in mm (inches)



12 voltage divider distribution

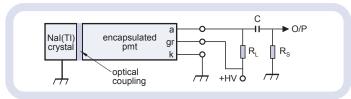


13 ordering information

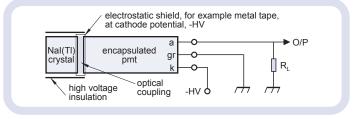
The 9110V16 meets the specification contained in this data sheet. If you want a different specification then please discuss your requirements with us. For customer specific requirements, ET Enterprises will change the 2 digit numeric suffix to indicate additional tests and selection.

14 applications with Nal(TI) crystals

The use with positive HV is recommended, as shown in the diagram below:



With negative HV, as shown in the next diagram, any material in contact with the window, for example the Nal(TI) crystal, must be maintained at cathode potential and insulated for safety. The interface between the NaI(TI) crystal and the pmt window must be shielded along the body of the housing.



These precautions are essential to prevent erratic behaviour.

*mumetal is a registered trademark of Magnetic Shield Corporation

ET Enterprises Limited 45 Riverside Way

Uxbridge UB8 2YF United Kingdom

tel: +44 (0) 1895 200880 fax: +44 (0) 1895 270873 e-mail: sales@et-enterprises.com web site: www.et-enterprises.com web site: www.electrontubes.com

ADIT Electron Tubes

300 Crane Street Sweetwater TX 79556 USA tel: (325) 235 1418 toll free: (800) 399 4557 fax: (325) 235 2872 e-mail: sales@electrontubes.com

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